

Surface Mount Super Fast Recovery Rectifier

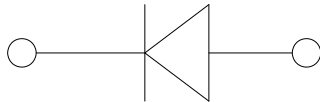


Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- High forward surge capability
- Super Fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Typical Applications

For use in high frequency rectification of power supplies, inverters, converters, and freewheeling diodes for consumer and telecommunication.



Mechanical Data

- **Package:** DO-214AA (SMB)
Molding compound meets UL 94 V-0 flammability rating, -compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Cathode line denotes the cathode end

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	UG3AB	UG3BB	UG3CB	UG3DB	UG3FB	UG3GB	UG3HB	UG3JB
Device marking code			UG3AB	UG3BB	UG3CB	UG3DB	UG3FB	UG3GB	UG3HB	UG3JB
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	V	50	100	150	200	300	400	500	600
Maximum RMS Voltage	V _{RMS}	V	35	70	105	140	210	280	350	420
Maximum DC blocking Voltage	V _{DC}	V	50	100	150	200	300	400	500	600
Average rectified output current @60Hz sine wave, resistance load, TL (Fig.1)	I _O	A	3.0							
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, T _j =25°C	I _{FSM}	A	100							
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, T _j =25°C			200							
Current squared time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	41.5							
Storage temperature	T _{stg}	°C	-55 ~ +150							
Junction temperature	T _j	°C	-55 ~ +150							

UG3AB THRU UG3JB

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	UG3AB	UG3BB	UG3CB	UG3DB	UG3FB	UG3GB	UG3HB	UG3JB
Maximum instantaneous forward voltage	V _F	V	I _{FM} =3.0A	0.92				1.25		1.7	
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	25						35	
Maximum DC reverse current at rated DC blocking voltage	I _R	μA	T _j =25°C	5							
			T _j =125°C	50							
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	65				58		55	

■Dynamic Characteristics

◆ UG3AB THRU UG3DB

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
Reverse Recovery Time	T _{RR}	ns	T _j =25°C	I _F =1A, di/dt=-50A/us V _{RM} =30V	-	30	-
			T _j =25°C	I _F =3A di/dt=-200A/us V _{RM} =100V	-	29	-
			T _j =125°C		-	35	-
Peak recovery current	I _{RRM}	A	T _j =25°C		-	3.8	-
			T _j =125°C		-	6.5	-
Reverse recovery charge	Q _{rr}	nC	T _j =25°C		-	39.9	-
			T _j =125°C		-	113.2	-
Non-repetitive avalanche energy	E _{AS}	mJ	T _j =25°C	I _R =3.6 A, L=15 mH	116.6	-	-

◆ UG3FB THRU UG3GB

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
Reverse Recovery Time	T _{RR}	ns	T _j =25°C	I _F =1A, di/dt=-50A/us V _{RM} =30V	-	29	-
			T _j =25°C	I _F =3A di/dt=-200A/us V _{RM} =200V	-	27	-
			T _j =125°C		-	41	-
Peak recovery current	I _{RRM}	A	T _j =25°C		-	3.2	-
			T _j =125°C		-	5.6	-
Reverse recovery charge	Q _{rr}	nC	T _j =25°C		-	43.0	-
			T _j =125°C		-	114.9	-
Non-repetitive avalanche energy	E _{AS}	mJ	T _j =25°C	I _R =0.7A, L=15 mH	3.7	-	-

◆ UG3HB THRU UG3JB

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
Reverse Recovery Time	T _{RR}	ns	T _j =25°C	I _F =1A, di/dt=-50A/us V _{RM} =30V	-	39	-
			T _j =25°C	I _F =3A di/dt=-200A/us V _{RM} =400V	-	40	-
			T _j =125°C		-	62	-
Peak recovery current	I _{RRM}	A	T _j =25°C		-	4.8	-
			T _j =125°C		-	7.8	-
Reverse recovery charge	Q _{rr}	nC	T _j =25°C		-	96.3	-
			T _j =125°C		-	241.4	-
Non-repetitive avalanche energy	E _{AS}	mJ	T _j =25°C	I _R =0.9A, L=15 mH	6.1	-	-

UG3AB THRU UG3JB

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	UG3AB	UG3BB	UG3CB	UG3DB	UG3FB	UG3GB	UG3HB	UG3JB
Typical Thermal resistance	R _{θJ-A} ⁽¹⁾	°C/W	65							
	R _{θJ-L} ⁽¹⁾		20							
	R _{θJ-C} ⁽¹⁾		18							

Note:
(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3" x 0.3" (8.0 mm x 8.0 mm) copper pad areas

■ Characteristics (Typical)

FIG.1: I_o-T_L Curve

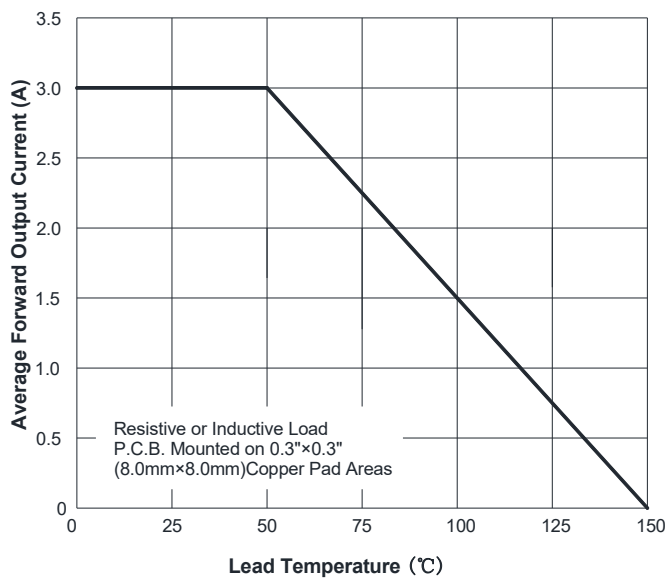


FIG.2: Forward Surge Current Capability

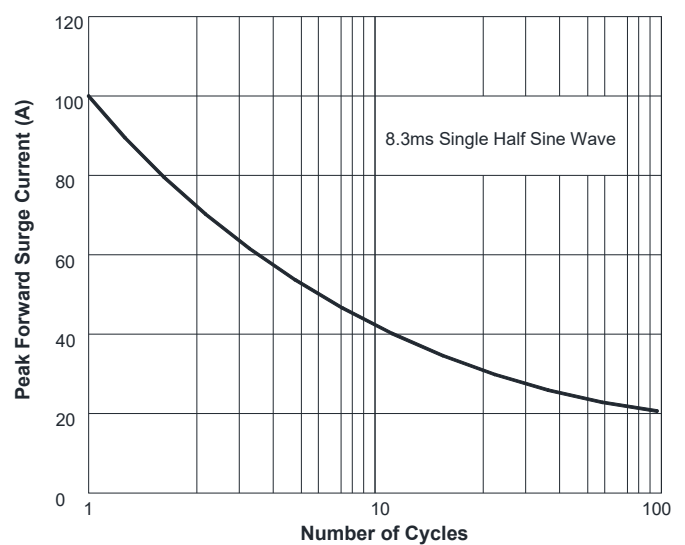


FIG.3: Typical Forward Voltage

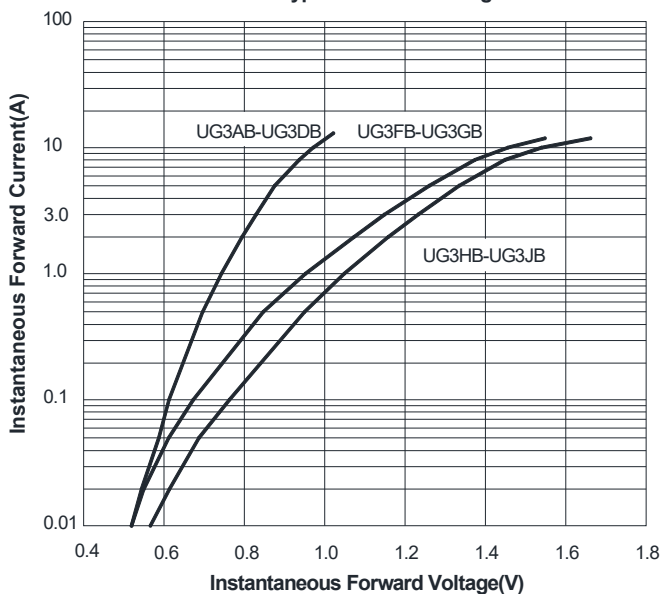
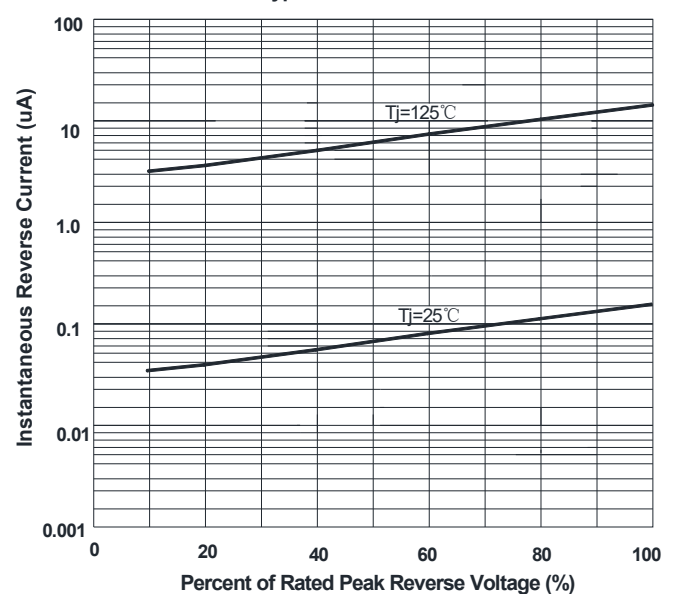
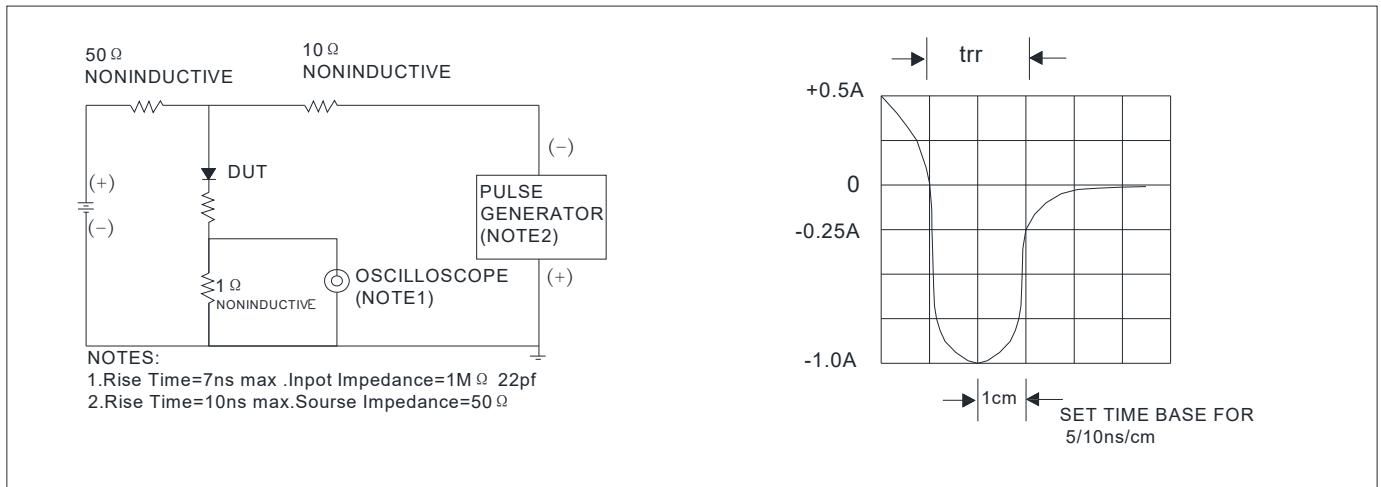


FIG.4: Typical Reverse Characteristics



UG3AB THRU UG3JB

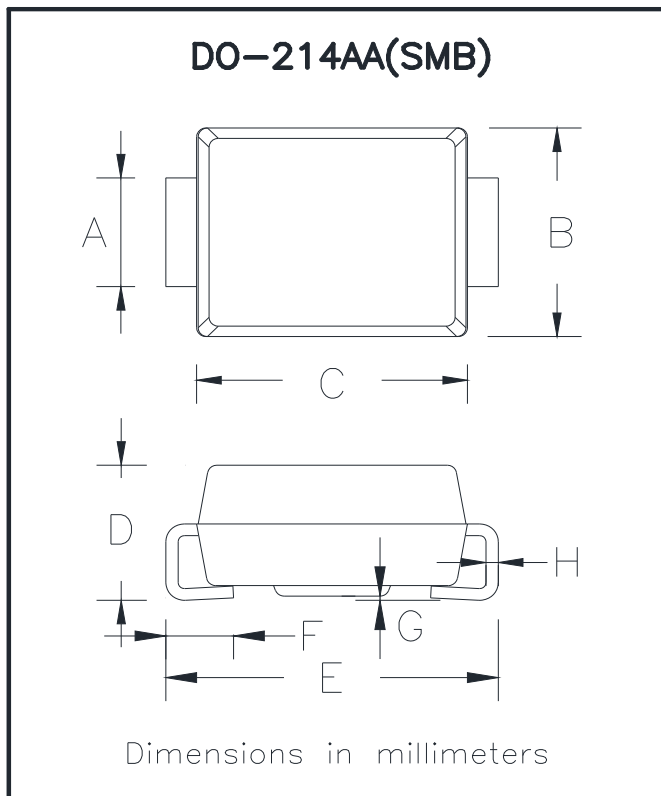
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



■ Ordering Information (Example)

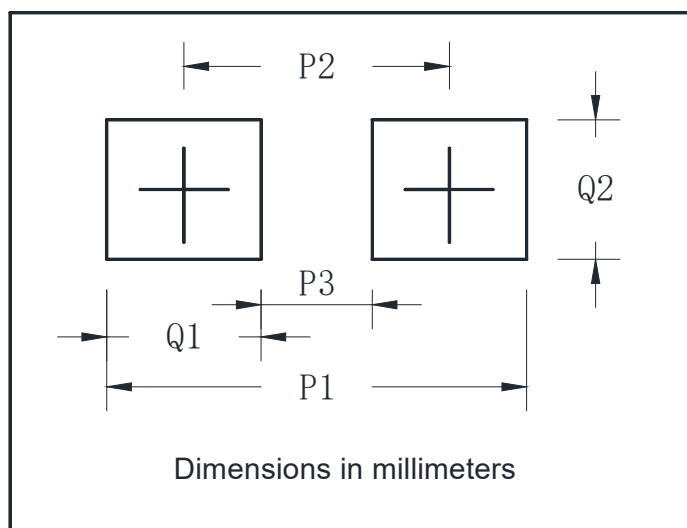
PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
UG3AB-UG3JB	F1	Approximate 0.096	3000	/	48000	13" reel
UG3AB-UG3JB	F2	Approximate 0.096	750	6000	24000	7" reel
UG3AB-UG3JB	F3	Approximate 0.096	500	4000	16000	7" reel

■ Outline Dimensions



DO-214AA(SMB)		
Dim	Min	Max
A	1.85	2.15
B	3.30	3.94
C	4.05	4.75
D	1.99	2.61
E	5.21	5.59
F	0.90	1.41
G	0.05	0.20
H	0.15	0.31

■ Suggested pad layout



DO-214AA(SMB)	
Dim	Millimeters
P1	6.8
P2	4.3
P3	1.8
Q1	2.5
Q2	2.3

Disclaimer

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